NSN 5961-01-074-2667

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-074-2667 **Inclosure Material:** Metal **Overall Length:** 0.700 inches **Overall Diameter:** 1.000 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, peak **Current Rating Per Characteristic:** 25.00 microamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 case and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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